

## Patent Assignment Abstract of Title

### Total Assignments: 1

**Application #:** 09928124

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**Inventors:** John Snyder, John Larson

Fabrication method for a device for regulating flow of electric current with high

**Title:** dielectric constant gate insulating layer and source/drain forming schottky contact or schottky-like region with substrate

### Assignment: 1

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**Conveyance:** ASSIGNMENT OF ASSIGNORS INTEREST (SEE DOCUMENT FOR DETAILS).

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